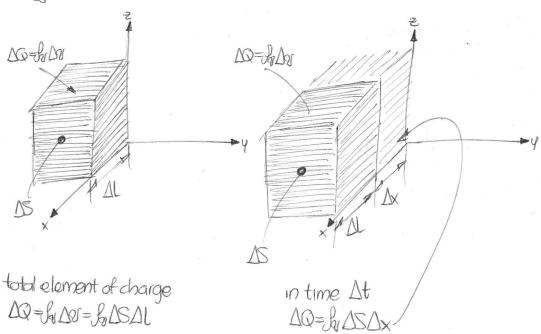
· Conductors, dielectrics, and capacitance

*Current and current density

J [A/m7] current density

CoNormal current density



$$\Delta I = \frac{\Delta Q}{\Delta t} = L_0 \Delta S \frac{\Delta x}{\Delta t} = L_0 \Delta S \sigma x$$

$$J_x = \frac{\Delta T}{\Delta S} = AOI_x$$

Locanvection current density

*Continuity of current

Previously

However, in a region bounded by a closed surface

autward flowing

Integral form of the continuity equation

$$I = \int_{K_1} (\vec{p} \cdot \vec{J}) dV = -\frac{dQ_i}{dt} = -\frac{d}{dt} \int_{V_{01}} h_i dv$$

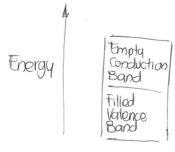
if we keep the surface constant

$$(\nabla \cdot T) = -\frac{\partial f_{ij}}{\partial t}$$

a Point form of the continuity equation

this equation indicates that the current, or charge per second, diverging from a small volume per unit volume is equal to the time rate of decrease of charge per unit volume at every point.





Conductor



Energy Gap

| od | |
|-------|-------------|
| lower | |
| ienue | |
| and | |
| | ed lence |

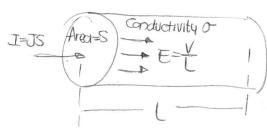
Insulator

Semiconductor

For an electron

- mobility of an electron (positive by definition)

-odrift velocity



Assuming that Jand Eare uniform

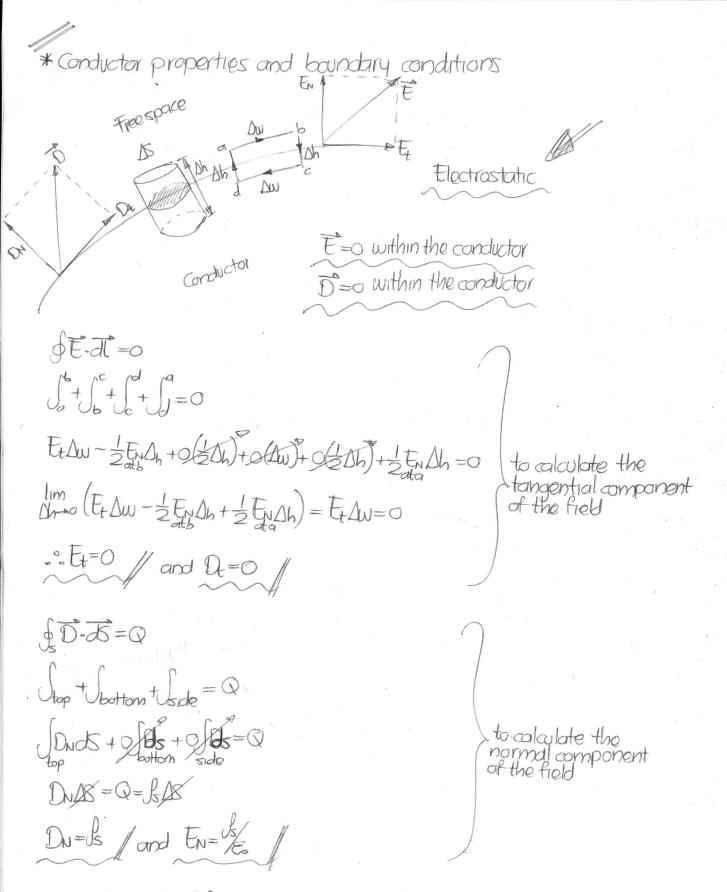
$$I = \int J \cdot J = JS = DJ = \frac{J}{S}$$

$$V_{ab} = -\int E \cdot J \cdot dI = -E \cdot L_{a} = E \cdot L_{a}$$

$$V = EL \Rightarrow DE = L$$

$$J = \frac{J}{S} = OE = OV \Rightarrow V = \frac{L}{OS} I, \quad \frac{L}{OS} = R$$

$$\therefore V = IR \int Ohmis Law$$



because E=0 E-dl=0 between any two points on the surface

- 1) The static electric field inside a conductor is zero
- z) The static electric field intensity at the surface of a conductor is everywhere directed normal to that surface
- 3) The conductor surface is an equipotential surface

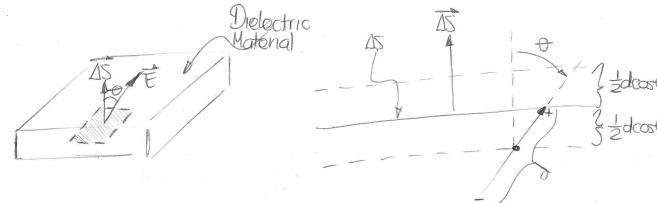
*Semiconductors

in metallic conductors

in semiconductors

*The nature of dielectric materials

if there are n dipoles per unit volume and we deal with a volume In



$$Q_b = -\oint \vec{P} \cdot \vec{ds}$$
 (the dot product is gonna be negative)

$$\vec{D} = \vec{e} \cdot \vec{E} + \vec{P}
\vec{Q} = \vec{b} \cdot \vec{D} \cdot \vec{dS} = \int_{S} ds ds, \quad \vec{b}_{1} = \vec{\nabla} \cdot \vec{D} \cdot$$

The linear relationship between Pand E is
$$P = x \in E$$
 electric susceptibility

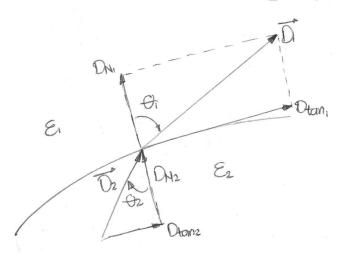
In anisotrapic materials

In summary, for isotropic materials

*Boundary conditions for perfect dielectric materials Region 2 Ez JE. at = 0 Etani Dw - EnDh - Etanz Dw + EnDh=0 lim (Frandw-En Ah-Etanz Dw+En Ah) = Franz Dw-Etanz Dw=0 (Flam - Etanz) DW = O Etani = Etanz to calculate the tangential component of the field

Generally

to calculate the normal component of the field



$$D_{N_1} = \Omega_{COS} \frac{\Theta_1}{\Theta_2}$$

$$D_{N_2} = D_{2OS} \frac{\Theta_2}{\Theta_2}$$

$$\frac{D_{tan_1}}{D_{tan_2}} = \frac{D_1 sin\theta_1}{D_2 sin\theta_2} = \frac{E_1}{E_2} = D E_2 D_1 sin\theta_1 = E_1 D_2 sin\theta_2$$

$$D_{N_1} = D_{N_2}$$

 $D_{1005}\theta_1 = D_{2005}\theta_2$

$$\frac{\mathcal{E}_{2}\mathcal{D}_{1}sin\theta_{1}}{\mathcal{D}_{2}cos\theta_{2}} = \frac{\mathcal{E}_{1}\mathcal{D}_{2}sin\theta_{2}}{\mathcal{D}_{2}cos\theta_{2}}$$

$$\mathcal{E}_{z} \tan \theta_{i} = \mathcal{E}_{i} \tan \theta_{z} = \mathcal{E}_{j} \frac{\tan \theta_{i}}{\tan \theta_{z}} = \frac{\mathcal{E}_{i}}{\mathcal{E}_{z}}$$

$$D_{2} = \sqrt{D_{N_{2}}^{2} + D_{tan_{2}}^{2}}$$

$$D_{N_{2}} = D_{2}^{2} \cos^{2}\theta_{2} = D_{1}^{2} \cos^{2}\theta_{1} = D_{N_{1}}^{2}$$

$$D_{tan_{2}} = D_{tan_{1}} \left(\frac{\mathcal{E}_{2}}{\mathcal{E}_{1}}\right) = D_{sin}\theta_{1} \left(\frac{\mathcal{E}_{2}}{\mathcal{E}_{1}}\right)$$

$$D_{tan_{2}}^{2} = D_{1}^{2} \sin^{2}\theta_{1} \left(\frac{\mathcal{E}_{2}}{\mathcal{E}_{1}}\right)^{2}$$

$$D_{2} = \sqrt{D_{1}^{2} \cos^{2}\theta_{1} + D_{1}^{2} \sin^{2}\theta_{1} \left(\frac{\mathcal{E}_{2}}{\mathcal{E}_{1}}\right)^{2}}$$

$$D_2 = \sqrt{D_1^2 \cos^2 \theta_1 + D_1^2 \sin^2 \theta_1 \left(\frac{E_2}{E_1}\right)^2}$$

$$D_2 = D_1 \sqrt{\cos^2 \theta_1 + \sin^2 \theta_1 \left(\frac{E_2}{E_1}\right)^2}$$

$$\mathcal{E}_{2}\mathcal{E}_{2}=\mathcal{E}_{1}\mathcal{E}_{1}\mathcal{E}_{2}\mathcal{E}_{1}\mathcal{E}_{3}\mathcal{E}_{1}\mathcal{E}_{1}\mathcal{E}_{2}\mathcal{E}_{3}\mathcal{E}_{1}\mathcal{E}_{3}\mathcal{E$$

$$E_2 = E_1 \sqrt{\cos^2 \Theta_1 \left(\frac{E_1}{E_2}\right)^2 + \sin^2 \Theta_1}$$

* Boundary conditions between conductor and dielectric

$$\vec{D} = 0$$
 (inside the conductor

-Any charge that is introduced internally within a conducting material arrives at the surface as a surface charge

$$\overrightarrow{\nabla} \cdot \overrightarrow{J} = -\frac{\partial h}{\partial t}$$
 Continuity equation

$$\nabla \cdot \sigma \vec{E} = -\frac{3k}{5t}, \vec{E} = \frac{\vec{D}}{\vec{\epsilon}}$$

$$h = -\frac{\varepsilon}{\sigma} \frac{\partial h}{\partial t}$$

$$-\frac{\sigma}{\varepsilon}\int_{0}^{t}dt=\int_{0}^{v}\frac{dv}{dv}$$

$$-\frac{\sigma}{\varepsilon}t = \ln\left(\frac{h}{h}\right)$$

$$ds = de^{-(0/\epsilon)t}$$

$$ds = de^{-(\sigma/\epsilon)t}$$

